# High Accuracy Ultra-low Iq, **500 mA Low Dropout** Regulator

The NCP3335 is a high performance low dropout regulator that entails all the required features for consumer electronics and encompasses a unique design technology that allows for a high accuracy of ±0.9% over line and load regulation. This device operates using a minimum output capacitance and is guaranteed to be stable using any type of capacitor.

With output voltage options at 2.5 V, 2.85 V, and 3.3 V, delivering 500 mA of current, this device is offered in a Micro8 package. It contains thermal protection, current limitation and is lead free.

#### **Features**

- High Accuracy Over Line and Load (±0.9% at 25°C)
- Ultra Low Dropout Voltage
- Low Noise
- Low Shutdown Current
- Low Dropout Voltage
- 2.6 V to 12 V Supply Range
- Thermal Shutdown Protection
- Current Limitation
- Minimum Output Capacitance of 1.0 μF Required for Stability
- Stable with Any Type of Capacitor (including MLCC)
- No Minimum Output Current Required for Stability
- Available in 2.5 V, 2.85 V, and 3.3 V Output Voltages (Please contact factory for other voltage options)
- These are Pb-Free Devices

## **Applications**

- PCMCIA Card
- Cellular Phones
- Camcoders and Cameras
- Networking Systems, DSL/Cable Modems
- Cable Set-Top Box
- MP3/CD Players
- DSP Supply



# ON Semiconductor®

http://onsemi.com



Micro8™ **DMR2 SUFFIX** CASE 846A

#### MARKING DIAGRAM



Α

Pin 1,2. V<sub>out</sub> 3. Sense Pin 4. GND 5. NR

6. SD (Shutdown Pin)

= LHX for 2.5 V XXX = LHY for 2.85 V = LHZ for 3.3 V

= Assembly Location = Year W = Work Week

## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

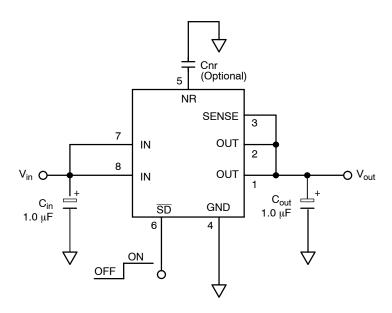


Figure 1. Typical Application Schematic

# **PIN FUNCTION DESCRIPTION**

Pin No.	Pin Name	Description		
1, 2	V <sub>out</sub>	gulated output voltage. Bypass to ground with $C_{out} \geq 1.0 \ \mu F$ .		
3	SENSE	For output voltage sensing, connect to Pins 1 and 2.		
4	GND	Power Supply Ground		
5	NR	Noise Reduction Pin. This is an optional pin used to further reduce noise.		
6	SD	Shutdown pin. When not in use, this pin should be connected to the input pin.		
7, 8	V <sub>in</sub>	Power Supply Input Voltage		

# **ABSOLUTE MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Input Voltage	V <sub>in</sub>	-0.3 to +16	V
Output Voltage	V <sub>out</sub>	-0.3 to V <sub>in</sub> +0.3	V
Shutdown Pin Voltage	V <sub>sh</sub>	-0.3 to +16	V
Thermal Characteristics Thermal Resistance, Junction-to-Air	$R_{ hetaJA}$	238	°C/W
Operating Junction Temperature Range	$T_J$	-40 to +150	°C
Storage Temperature Range	T <sub>stg</sub>	-50 to+150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

NOTE: This device series contains ESD protection and exceeds the following tests:

Human Body Model (HBM) JESD 22-A114-B

Machine Model (MM) JESD 22-A115-A

# $\textbf{ELECTRICAL CHARACTERISTICS - 2.5 V} \ (V_{out} = 2.5 \ V \ typical, \ V_{in} = 2.9 \ V, \ T_{A} = -40^{\circ}C \ to \ +85^{\circ}C, \ unless \ otherwise \ noted)$

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) $V_{in}$ = 2.9 V to 6.5 V, $I_{load}$ = 0.1 mA to 500 mA, $T_J$ = 25°C	V <sub>out</sub>	-0.9% 2.477	2.5	+0.9% 2.523	٧
Output Voltage (Accuracy) $V_{in}$ = 2.9 V to 6.5 V, $I_{load}$ = 0.1 mA to 500 mA, $T_J$ = 0°C to +85°C	V <sub>out</sub>	-1.4% 2.465	2.5	+1.4% 2.535	V
Output Voltage (Accuracy), (Note 1) $V_{in}$ = 2.9 V to 6.5 V, $I_{load}$ = 0.1 mA to 500 mA, $T_J$ = -40°C to +150°C	V <sub>out</sub>	-1.5% 2.462	2.5	+1.5% 2.538	V
Line Regulation $V_{in} = 2.9 \text{ V to } 6.5 \text{ V}, I_{load} = 0.1 \text{ mA}$	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation V <sub>in</sub> = 2.9 V, I <sub>load</sub> = 0.1 mA to 500 mA	Load <sub>Reg</sub>		0.04		mV/mA
Dropout voltage  I <sub>load</sub> = 500 mA (Note 2)  I <sub>load</sub> = 300 mA (Note 2)  I <sub>load</sub> = 50 mA  I <sub>load</sub> = 0.1mA	V <sub>DO</sub>			340 230 110 10	mV
Peak Output Current	I <sub>pk</sub>	500	700		mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA (Note 2)}$ $I_{load} = 300 \text{ mA (Note 2)}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 5.1 \text{ mA}$ In Dropout $V_{in} = 2.4 \text{ V, } I_{load} = 0.1 \text{ mA}$ In Shutdown $S_D = 0 \text{ V}$	I <sub>GND</sub>		9.0 4.6 0.8 -	14 7.5 2.5 190 500	mA μA μA μA
Output Noise $C_{nr}$ = 0 nF, $I_{load}$ = 500 mA, f = 10 Hz to 100 kHz, $C_{out}$ = 10 $\mu$ F $C_{nr}$ = 10 nF, $I_{load}$ = 500 mA, f = 10 Hz to 100 kHz, $C_{out}$ = 10 $\mu$ F	V <sub>noise</sub>		56 35		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V
$\overline{\text{SD}}$ Input Current, $V_{\text{SD}}$ = 0 V to 0.4 V or $V_{\text{SD}}$ = 2.0 V to $V_{\text{in}}$	I <sub>SD</sub>		0.07	1.0	μΑ
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μΑ

<sup>1.</sup> For proper operation below  $T_J = 0^{\circ}C$ , please refer to typical graphs. 2.  $T_A$  must be greater than  $0^{\circ}C$ .

# $\textbf{ELECTRICAL CHARACTERISTICS - 2.85 V} \ (V_{out} = 2.85 \ V \ typical, \ V_{in} = 3.25 \ V, \ T_{A} = -40 ^{\circ}C \ to \ +85 ^{\circ}C, \ unless \ otherwise \ noted)$

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) $V_{in}$ = 3.25 V to 6.85 V, $I_{load}$ = 0.1 mA to 500 mA, $T_J$ = 25°C	V <sub>out</sub>	-0.9% 2.824	2.85	+0.9% 2.876	V
Output Voltage (Accuracy) $V_{in} = 3.25 \text{ V}$ to 6.85 V, $I_{load} = 0.1 \text{ mA}$ to 500 mA, $T_J = 0^{\circ}\text{C}$ to +85°C	V <sub>out</sub>	-1.4% 2.810	2.85	+1.4% 2.890	٧
Output Voltage (Accuracy) (Note 3) $V_{in} = 3.25 \text{ V to } 6.85 \text{ V, } I_{load} = 0.1 \text{ mA to } 500 \text{ mA, } T_J = -40^{\circ}\text{C to } +150^{\circ}\text{C}$	V <sub>out</sub>	-1.5% 2.807	2.85	+1.5% 2.893	V
Line Regulation $V_{in} = 3.25 \text{ V to } 6.85 \text{ V, } I_{load} = 0.1 \text{ mA}$	Line <sub>Reg</sub>		0.04		mV/V
Load Regulation $V_{in} = 3.25 \text{ V}, I_{load} = 0.1 \text{ mA to } 500 \text{ mA}$	Load <sub>Reg</sub>		0.04		mV/mA
Dropout voltage   I <sub>load</sub> = 500 mA   I <sub>load</sub> = 300 mA   I <sub>load</sub> = 50 mA   I <sub>load</sub> = 0.1mA	V <sub>DO</sub>			340 230 110 10	mV
Peak Output Current	I <sub>pk</sub>	500	700		mA
Thermal Shutdown	TJ		160		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA (Note 4)}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$ In Dropout $V_{in} = 2.75 \text{ V, } I_{load} = 0.1 \text{ mA}$ In Shutdown $SD = 0 \text{ V}$	I <sub>GNDsh</sub>		9.0 4.6 0.8 - -	14 7.5 2.5 190 500	mA μA μA μA
Output Noise $C_{nr}=0$ nF, $I_{load}=500$ mA, f = 10 Hz to 100 kHz, $C_{out}=10$ $\mu$ F $C_{nr}=10$ nF, $I_{load}=500$ mA, f = 10 Hz to 100 kHz, $C_{out}=10$ $\mu$ F	V <sub>noise</sub>		61 40		μVrms μVrms
Shutdown Threshold Voltage ON Threshold Voltage OFF		2.0		0.4	V
S <sub>D</sub> Input Current, V <sub>SD</sub> = 0 V to 0.4 V or V <sub>SD</sub> = 2.0 V to V <sub>in</sub>	I <sub>SD</sub>		0.07	1.0	μΑ
Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μΑ

<sup>3.</sup> For proper operation below  $T_J = 0^{\circ}C$ , please refer to typical graphs. 4.  $T_A$  must be greater than  $0^{\circ}C$ .

# $\textbf{ELECTRICAL CHARACTERISTICS - 3.3 V} \ (V_{out} = 3.3 \ V \ typical, \ V_{in} = 3.7 \ V, \ T_{A} = -40^{\circ}C \ to \ +85^{\circ}C, \ unless \ otherwise \ noted)$

$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Characteristic	Symbol	Min	Тур	Max	Unit
V <sub>In</sub> = 3.7 V tò 7.3 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>J</sub> = 0°C to +85°C         3.254         3.346           Output Voltage (Accuracy)         V <sub>out</sub> = 3.7 V to 7.3 V, I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>J</sub> = -40°C to +150°C         V <sub>out</sub> = -1.5% a.250         3.3         +1.5% a.350         V           Line Regulation V <sub>In</sub> = 3.7 V to 7.3 V, I <sub>load</sub> = 0.1 mA         Line Regulation         Load Reg         0.04         mV/mA           Load Regulation V <sub>In</sub> = 3.7 V, I <sub>load</sub> = 0.1 mA to 500 mA         Load Regulation         VDO         340 a.340 a.34	Output Voltage (Accuracy) $V_{in} = 3.7 \text{ V to } 7.3 \text{ V, } I_{load} = 0.1 \text{ mA to } 500 \text{ mA, } T_J = 25^{\circ}\text{C}$	$V_{out}$		3.3		V
Vin = 3.7 V to 7.3 V,   I <sub>load</sub> = 0.1 mA to 500 mA, T <sub>J</sub> = -40°C to +150°C   3.250   3.350     Line Regulation   Vin = 3.7 V to 7.3 V,   I <sub>load</sub> = 0.1 mA     Load Regulation   Vin = 3.7 V,   I <sub>load</sub> = 0.1 mA to 500 mA     Load Regulation   Vin = 3.7 V,   I <sub>load</sub> = 0.1 mA to 500 mA     Dropout Voltage   I <sub>load</sub> = 500 mA     I <sub>load</sub> = 50 mA     I <sub>load</sub> = 0.1 mA     In Dropout     Vin = 3.2 V,   I <sub>load</sub> = 0.1 mA     In Shutdown     S <sub>D</sub> = 0 V     Output Noise     C <sub>m</sub> = 0 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 500 mA, f = 10 Hz to 100 kHz, C <sub>out</sub> = 10 μF     C <sub>rr</sub> = 10 nF,   I <sub>load</sub> = 5		V <sub>out</sub>		3.3		V
V <sub>In</sub> = 3.7 V to 7.3 V, I <sub>load</sub> = 0.1 mA		V <sub>out</sub>		3.3		V
Vin = 3.7 V. I <sub>load</sub> = 0.1 mA to 500 mA       VDO       340 230 340 230 110 230 mA 110 110 110 110 110 110 110 110 110 11		Line <sub>Reg</sub>		0.04		mV/V
I <sub>load</sub> = 500 mA   I <sub>load</sub> = 500 mA   I <sub>load</sub> = 500 mA   I <sub>load</sub> = 50 mA   I <sub>load</sub> = 500 mA   I <sub>load</sub> = 50 mA	9	Load <sub>Reg</sub>		0.04		mV/mA
Thermal Shutdown  TJ 160 °C  Ground Current In Regulation Iload = 500 mA (Note 5) Iload = 300 mA Iload = 50 mA Iload = 0.1 mA  In Dropout Vin = 3.2 V, Iload = 0.1 mA  In Shutdown SD = 0 V  Output Noise Cnr = 0 nF, Iload = 500 mA, f = 10 Hz to 100 kHz, Cout = 10 μF Cnr = 10 nF, Iload = 500 mA, f = 10 Hz to 100 kHz, Cout = 10 μF Threshold Voltage ON Threshold Voltage ON Threshold Voltage OFF  SD Input Current, VSD = 0 V to 0.4 V or VSD = 2.0 V to Vin  I GNDsh  IGNDsh	I <sub>load</sub> = 500 mA I <sub>load</sub> = 300 mA I <sub>load</sub> = 50 mA	V <sub>DO</sub>			230 110	mV
Ground Current       In Regulation       IgnD       IgnD       14 mA       mA         I load = 500 mA (Note 5)       9.0 14 mA       4.6 7.5 0.8 2.5 mA       0.8 mA       0.0 mA	Peak Output Current	lpk	500	700		mA
In Regulation	Thermal Shutdown	TJ		160		°C
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	In Regulation I <sub>load</sub> = 500 mA (Note 5) I <sub>load</sub> = 300 mA I <sub>load</sub> = 50 mA	I <sub>GND</sub>		4.6	7.5 2.5	
Output Noise $C_{nr} = 0 \text{ nF, } I_{load} = 500 \text{ mA, } f = 10 \text{ Hz to } 100 \text{ kHz, } C_{out} = 10  \mu\text{F}$ $C_{nr} = 10 \text{ nF, } I_{load} = 500 \text{ mA, } f = 10 \text{ Hz to } 100 \text{ kHz, } C_{out} = 10  \mu\text{F}$ $C_{nr} = 10 \text{ nF, } I_{load} = 500 \text{ mA, } f = 10 \text{ Hz to } 100 \text{ kHz, } C_{out} = 10  \mu\text{F}$ $Shutdown$ $Threshold Voltage ON$ $Threshold Voltage OFF$ $S_D \text{ Input Current, } V_{SD} = 0 \text{ V to } 0.4 \text{ V or } V_{SD} = 2.0 \text{ V to } V_{in}$ $I_{SD}$ $0.07$ $1.0$ $0.07$	$V_{in} = 3.2 \text{ V}, I_{load} = 0.1 \text{ mA}$			-	500	μΑ
$\begin{array}{c} C_{nr} = 0 \text{ nF, } I_{load} = 500 \text{ mA, } f = 10 \text{ Hz to } 100 \text{ kHz, } C_{out} = 10  \mu\text{F} \\ C_{nr} = 10 \text{ nF, } I_{load} = 500 \text{ mA, } f = 10 \text{ Hz to } 100 \text{ kHz, } C_{out} = 10  \mu\text{F} \\ \end{array}$	$S_D = 0 V$	$I_{GNDsh}$		0.07	1.0	μΑ
Threshold Voltage ON Threshold Voltage OFF	$\dot{C}_{nr}$ = 0 nF, $I_{load}$ = 500 mA, f = 10 Hz to 100 kHz, $C_{out}$ = 10 $\mu$ F	V <sub>noise</sub>				
	Threshold Voltage ON		2.0		0.4	
Output Current In Shutdown Mode, $V_{out} = 0 \text{ V}$ $I_{OSD}$ 0.07 1.0 $\mu A$	$S_D$ Input Current, $V_{SD}$ = 0 V to 0.4 V or $V_{SD}$ = 2.0 V to $V_{in}$	I <sub>SD</sub>		0.07	1.0	μΑ
	Output Current In Shutdown Mode, V <sub>out</sub> = 0 V	I <sub>OSD</sub>		0.07	1.0	μΑ

<sup>5.</sup> T<sub>A</sub> must be greater than 0°C.

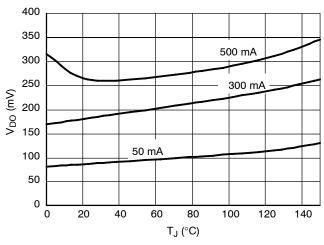


Figure 2. Dropout Voltage vs. Temperature

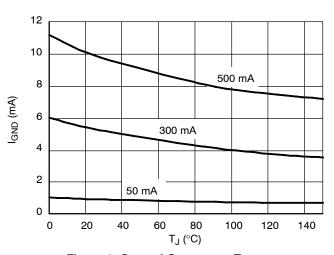


Figure 3. Ground Current vs. Temperature

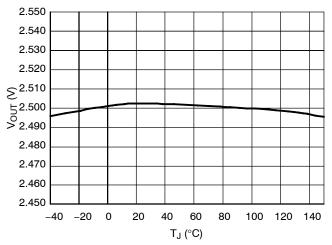


Figure 4. Output Voltage vs. Temperature

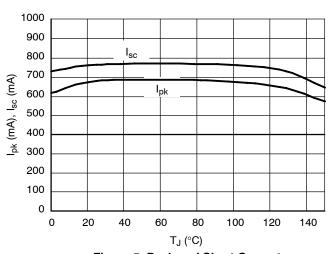


Figure 5. Peak and Short Current vs. Temperature

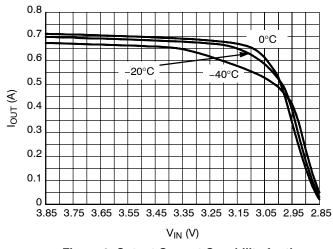


Figure 6. Output Current Capability for the 2.85 V Version

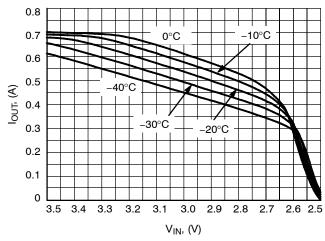


Figure 7. Output Current Capability for the 2.5 V Version

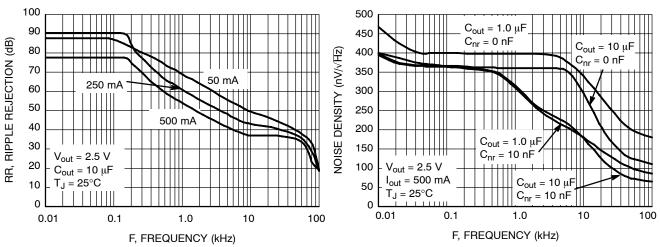


Figure 8. Ripple Rejection vs. Frequency

Figure 9. Output Noise Density

# **ORDERING INFORMATION**

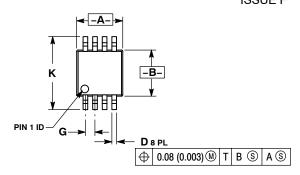
Device	Nominal Output Voltage	Package	Shipping <sup>†</sup>
NCP3335DMR2250G	2.5 V	Micro8 (Pb-Free)	4000 / Tape & Reel
NCP3335DMR2285G	2.85 V	Micro8 (Pb-Free)	4000 / Tape & Reel
NCP3335DMR2330G	3.3 V	Micro8 (Pb-Free)	4000 / Tape & Reel

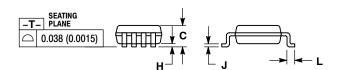
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>Please contact factory for other voltage options.

### PACKAGE DIMENSIONS

### Micro8 CASE 846A-02 **ISSUE F**



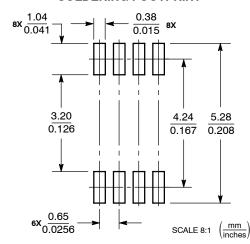


#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION, INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010)
- 846A-01 OBSOLETE, NEW STANDARD 846A-02.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	2.90	3.10	0.114	0.122	
В	2.90	3.10	0.114	0.122	
С		1.10		0.043	
D	0.25	0.40	0.010	0.016	
G	0.65	BSC	0.026 BSC		
Н	0.05	0.15	0.002	0.006	
J	0.13	0.23	0.005	0.009	
K	4.75	5.05	0.187	0.199	
L	0.40	0.70	0.016	0.028	

### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

The products described herein NCP3335, may be covered by one or more of the following U.S. patents; 5,920,184, 5,966,004, and 5,834,926. There may be other patents pending.

Micro8 is a trademark of International Rectifier.

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### **PUBLICATION ORDERING INFORMATION**

### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

N. American Technical Support: 800-282-9855 Toll Free

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative